



AND412HB

InGaN High Intensity Blue Light Emission

- 5 mm (T1-3/4) Package
- Available on tape and reel
- Peak wavelength ($\lambda p = 470$ nm) high bright emission
- All plastic mold type, clear colorless lens
- Low drive current: 1 to 20 mA DC
- Excellent On-Off contrast ratio
- Fast response time, capable of pulse operation
- High power intensity suitable for indoor/outdoor applications
- High reliability

Maxim um Ratings (T $_a = 25$ °C)

Characteristics	Symbol	Rating	Unit
Forward Current	I _F	30	mA
Reverse Voltage	V _R	5	V
Power Dissipation	P _D	120	mW
Operating Temperature Range	T _{Opr}	-40 to 85	С
Storage Temperature Range	T _{Sig}	-40 to 100	С

Electr o-Optical Characteristics (T $_a = 25^{\circ}$ C)

Characteristics	Symbol	Test Condition	Minimum	Typical	Maximum	Unit
Forward Voltage	V _F	I _F = 20 mA	_	3.5	4.0	V
Reverse Current	I _R	V _R = 5V	_	-	10	μA
Luminous Intensity	I _V	I _F = 20 mA	400.0	530.0	_	mcd
Peak Emission Wavelength	λ _P	I _F = 20 mA	_	470	_	nm
Spectral Line Half Width	Δλ	I _F = 20 mA	_	40	_	nm
Dominant Wavelength	λd	I _F = 20 mA	464	-	468	nm
Full Viewing Angle	2 θ 1/2	I _V = 1/2 Peak	_	12	_	degree

Precaution

Please be careful of the following:

- 1. Soldering temperature: 260 C max.
 - Soldering time: 5 sec. max.
 - Soldering portion of lead: up to 1.6 mm from the body of the device
- 2. The lead can be formed up to 5 mm from the body of the device without forming stress. Soldering should be performed after the lead forming.



InGaN High Intensity Blue Light Emission Ultra Bright LED Lamps: Type











